

2SC5957

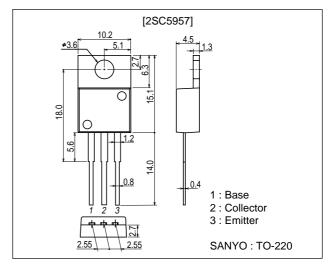
# **Switching Regulator Applications**

#### **Features**

- · High breakdown voltage and high reliability.
- · High-speed switching.
- · Wide ASO.
- · Adoption of MBIT process.

### **Package Dimensions**

unit : mm 2010C



# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		500	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		10	Α
Collector Current (Pulse)	ICP	PW≤300μs, duty cycle≤10%	20	Α
Base Current	IΒ		3.5	Α
Callagter Dissipation	Do.		1.75	W
Collector Dissipation	PC	Tc=25°C	50	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =400V, I <sub>E</sub> =0			10	μΑ
Emitter Cutoff Current	IEBO	VEB=5V, IC=0			10	μА

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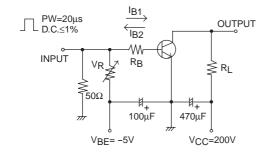
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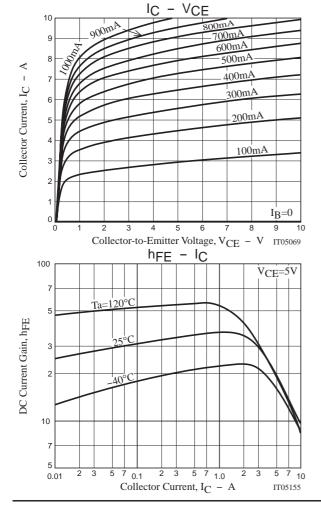
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol	min	typ	max	Uniii	
	hFE1	V <sub>CE</sub> =5V, I <sub>C</sub> =1.2A	20*		50*	
DC Current Gain	hFE2	V <sub>CE</sub> =5V, I <sub>C</sub> =6A	10			
	hFE3	VCE=5V, IC=1mA	10			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =1.2A		15		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		80		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=6A, IB=1.2A			0.8	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =6A, I <sub>B</sub> =1.2A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	7			V
Turn-ON Time	ton	I <sub>C</sub> =7A, I <sub>B1</sub> =1.4A, I <sub>B2</sub> =-2.8A, R <sub>L</sub> =28.6Ω, V <sub>CC</sub> =200V			0.5	μs
Storage Time	tstg	I <sub>C</sub> =7A, I <sub>B1</sub> =1.4A, I <sub>B2</sub> =-2.8A, R <sub>L</sub> =28.6Ω, V <sub>CC</sub> =200V			2.5	μs
Fall Time	tf	I <sub>C</sub> =7A, I <sub>B1</sub> =1.4A, I <sub>B2</sub> =-2.8A, R <sub>L</sub> =28.6Ω, V <sub>CC</sub> =200V			0.3	μs

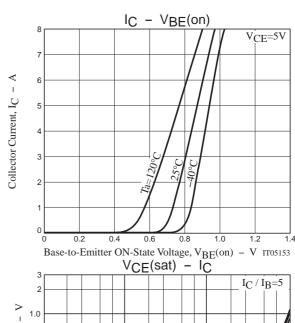
\*: The hFE1 of the 2SC5957 is classified as follows.

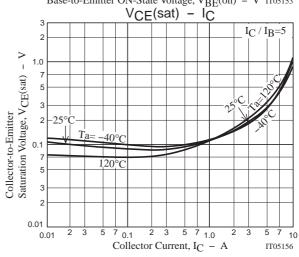
Rank	М	N		
hFE	20 to 40	30 to 50		

# **Switching Time Test Circuit**

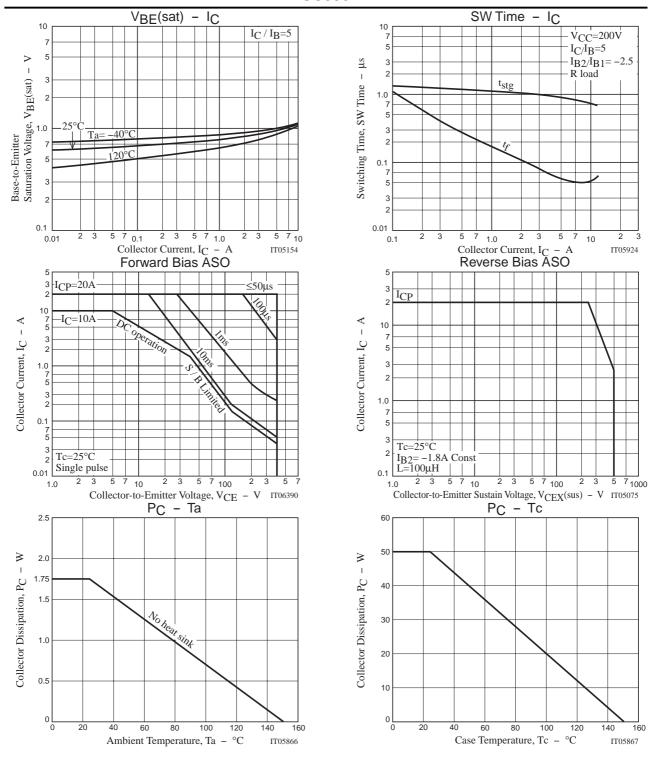








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